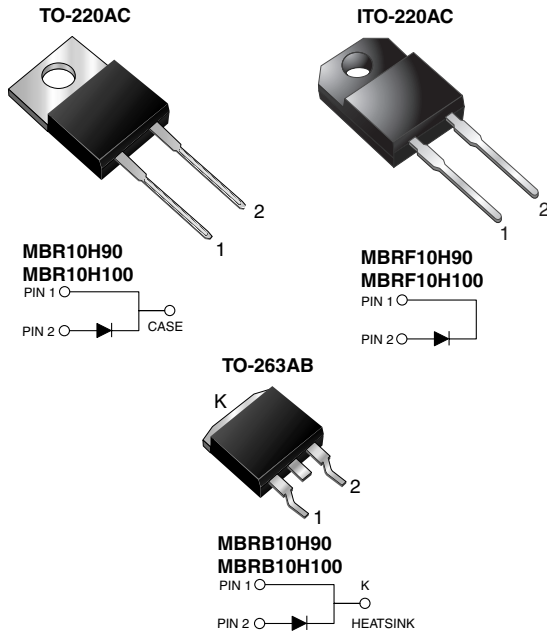


High-Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AC and ITO-220AC package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AC, ITO-220AC, TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	10 A
V_{RRM}	90 V, 100 V
I_{FSM}	250 A
V_F	0.64 V
I_R	4.5 μ A
T_J max.	175 °C

MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	MBR10H90	MBR10H100	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	90	100	V
Working peak reverse voltage	V_{RWM}	90	100	V
Maximum DC blocking voltage	V_{DC}	90	100	V
Maximum average forward rectified current	$I_{F(AV)}$	10		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	250		A
Peak repetitive reverse current at $t_p = 2$ μ s, 1 kHz	I_{RRM}	0.5		A
Voltage rate of change (rated V_R)	dV/dt	10 000		V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	- 65 to + 175		°C
Isolation voltage (ITO-220AC only) from terminal to heatsink $t = 1$ min	V_{AC}	1500		V

MBR(F,B)10H90 & MBR(F,B)10H100

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ELECTRICAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	$I_F = 10\text{ A}$	$T_C = 25\text{ }^\circ\text{C}$	V_F	0.77	V
	$I_F = 10\text{ A}$	$T_C = 125\text{ }^\circ\text{C}$		0.64	
	$I_F = 20\text{ A}$	$T_C = 25\text{ }^\circ\text{C}$		0.88	
	$I_F = 20\text{ A}$	$T_C = 125\text{ }^\circ\text{C}$		0.73	
Maximum reverse current at working peak reverse voltage ⁽¹⁾			I_R	4.5	μA mA
				$T_J = 125\text{ }^\circ\text{C}$	

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance	$R_{\theta JC}$	2.7	5.8	2.7	$^\circ\text{C/W}$

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AC	MBR10H100-E3/45	1.80	45	50/tube	Tube
ITO-220AC	MBRF10H100-E3/45	1.94	45	50/tube	Tube
TO-263AB	MBRB10H100-E3/45	1.33	45	50/tube	Tube
TO-263AB	MBRB10H100-E3/81	1.33	81	800/reel	Tape and reel
TO-220AC	MBR10H100HE3/45 ⁽¹⁾	1.80	45	50/tube	Tube
ITO-220AC	MBRF10H100HE3/45 ⁽¹⁾	1.94	45	50/tube	Tube
TO-263AB	MBRB10H100HE3/45 ⁽¹⁾	1.33	45	50/tube	Tube
TO-263AB	MBRB10H100HE3/81 ⁽¹⁾	1.33	81	800/reel	Tape and reel

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

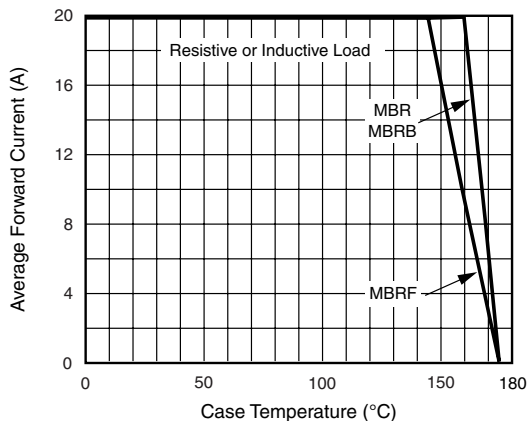


Figure 1. Forward Current Derating Curve

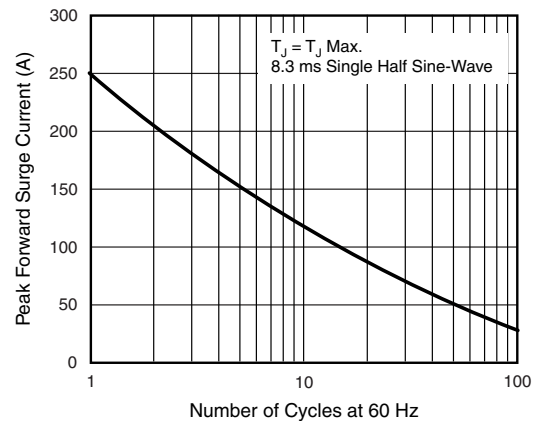


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

MBR(F,B)10H90 & MBR(F,B)10H100

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

